

## CSM2303S23

### 30V P-Channel Enhancement Mode MOSFET

**Voltage**

**-30 V**

**Current**

**-3A**

#### Features

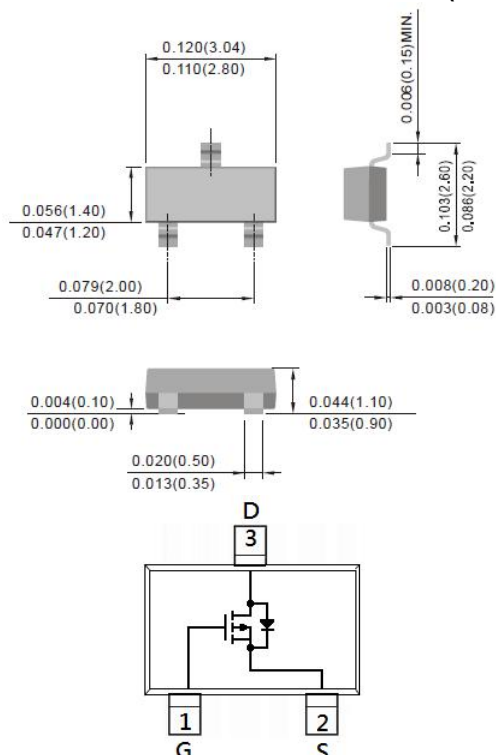
- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-2.9A < 110m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-1.9A < 130m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.

#### Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams

**SOT-23**

**Unit: inch(mm)**



### Maximum Ratings and Thermal Characteristics ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-30	V
Gate-Source Voltage		$V_{GS}$	+20	V
Continuous Drain Current		$I_D$	-3	A
Pulsed Drain Current		$I_{DM}$	-12	A
Power Dissipation	$T_a=25^{\circ}C$	$P_D$	1.25	W
	Derate above $25^{\circ}C$		10	mW/ $^{\circ}C$
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^{\circ}C$
Typical Thermal resistance Junction to Ambient (Note 3)		$R_{\theta JA}$	100	$^{\circ}C/W$

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## Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.31	-2.1	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-2.9A	-	92	110	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.9A	-	120	130	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	±10	±100	nA
Dynamic						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-15V, I <sub>D</sub> =-2.9A, V <sub>GS</sub> =-10V (Note 1,2)	-	9.8	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.5	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	2.2	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	396	-	pF
Output Capacitance	C <sub>oss</sub>		-	47	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	36	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =-15V, I <sub>D</sub> =-2.9A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω (Note 1,2)	-	5	-	ns
Turn-On Rise Time	tr			30		
Turn-Off Delay Time	td <sub>(off)</sub>		-	25	-	
Turn-Off Fall Time	tf		-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>s</sub>	---	-	-	-1.5	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>s</sub> =-1.0A, V <sub>GS</sub> =0V		-0.77	-1.2	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited

## CSM2303S23

### TYPICAL CHARACTERISTIC CURVES

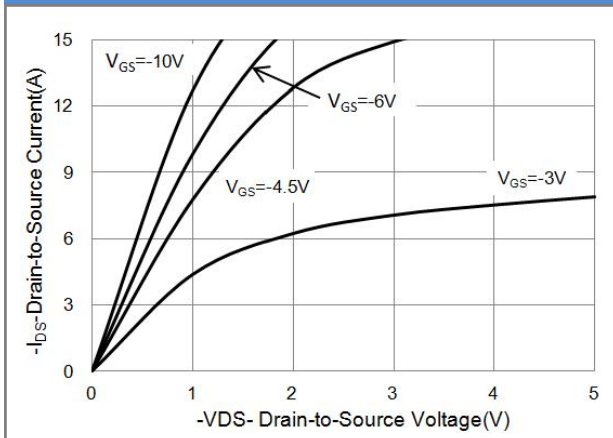


Fig.1 On-Region Characteristics

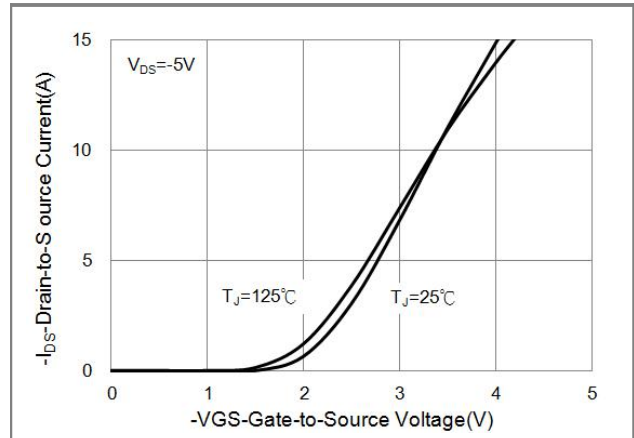


Fig.2 Transfer Characteristics

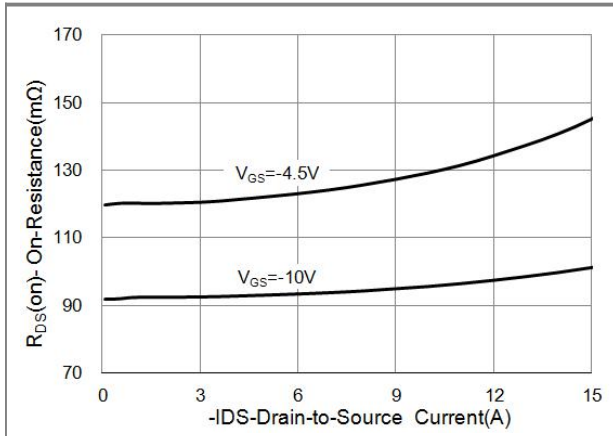


Fig.3 On-Resistance vs. Drain Current

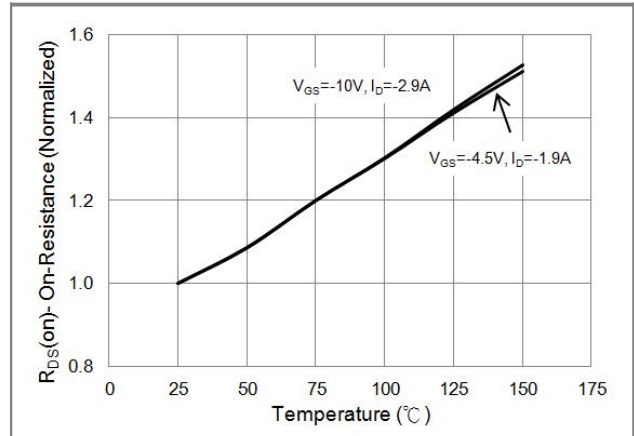


Fig.4 On-Resistance vs. Junction temperature

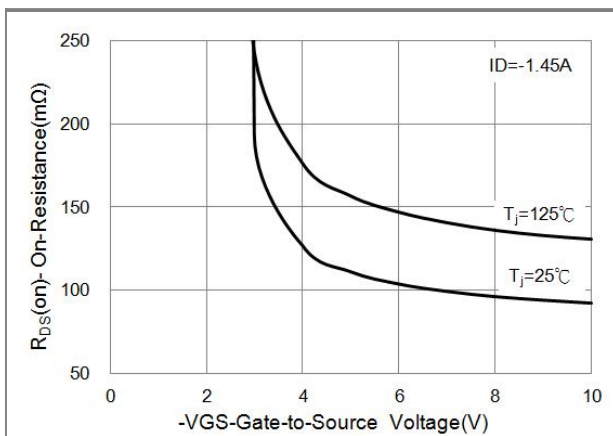


Fig.5 On-Resistance Variation with VGS.

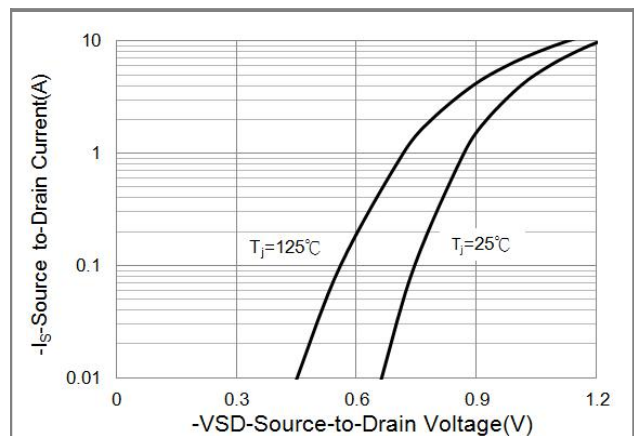


Fig.6 Body Diode Characteristics

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### TYPICAL CHARACTERISTIC CURVES

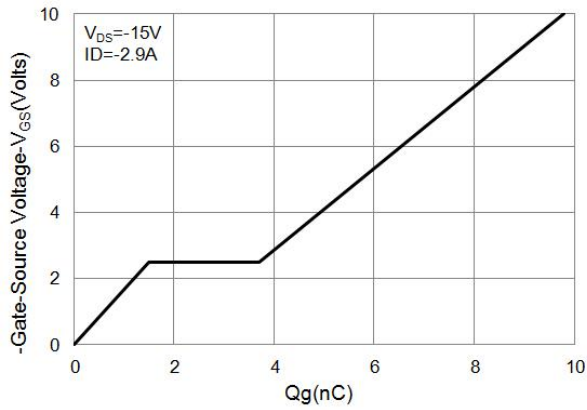


Fig.7 Gate-Charge Characteristics

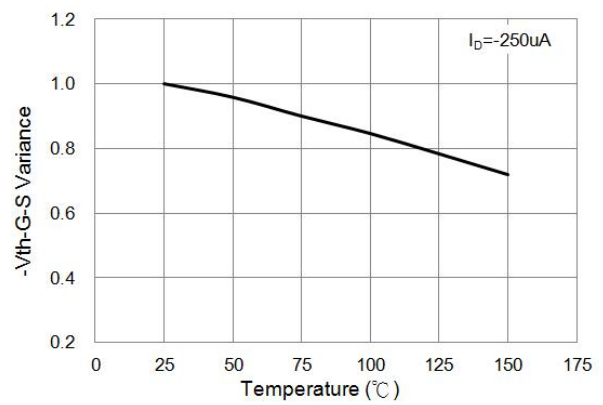


Fig.8 Threshold Voltage Variation with Temperature

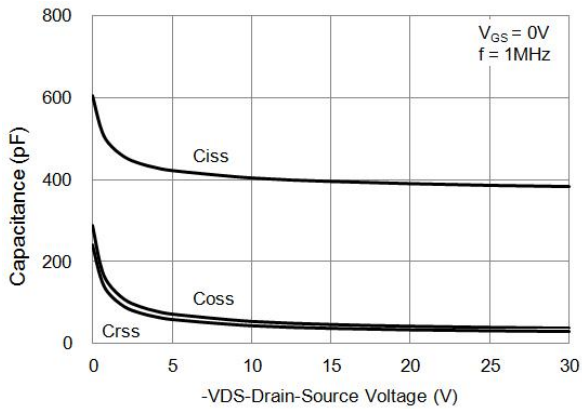


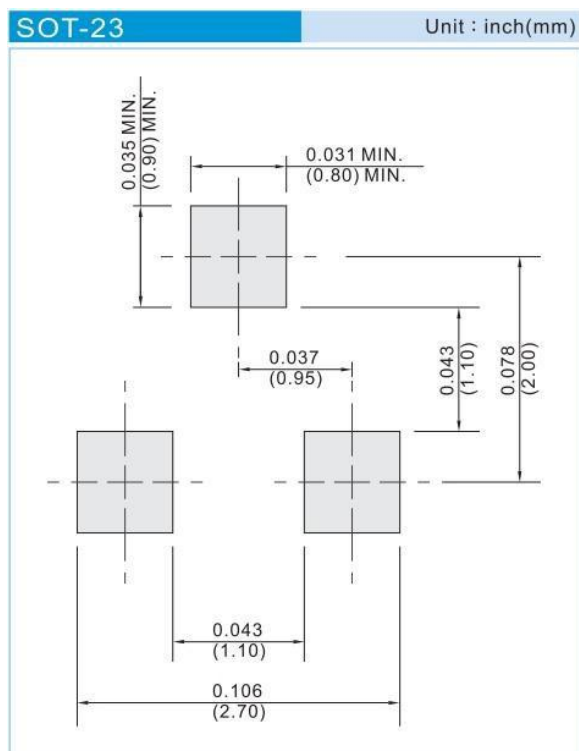
Fig.9 Capacitance vs. Drain-Source Voltage

## CSM2303S23

### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type
CSM2303S23	SOT-23	3K pcs / 7" reel

### MOUNTING PAD LAYOUT



## **CSM2303S23**

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